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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/689,332	10/20/2003	Minna Hovinen	TWI-12730	4186	
75	90 07/13/2004		EXAM	EXAMINER	
STALLMAN & POLLOCK LLP			SIKDER, MOHAMMAD YUNUS		
Suite 290 121 Spear Street	t		ART UNIT	PAPER NUMBER	
San Francisco, CA 94105			2872		
			DATE MAILED: 07/13/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application	٧٥.	Applicant(s)			
Office Action Summary		10/689,332		HOVINEN ET AL.			
		Examiner		Art Unit			
	<u>`</u>	MOHAMMAD		2872			
Period fo	The MAILING DATE of this communication apor Reply	ppears on the co	ver sh et with th c	orr spond no ac	idr ss		
THE - Exte after - If the - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPL MAILING DATE OF THIS COMMUNICATION. nsions of time may be available under the provisions of 37 CFR 1. SIX (6) MONTHS from the mailing date of this communication. e period for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period are to reply within the set or extended period for reply will, by statuting received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	.136(a). In no event, I ply within the statutory d will apply and will ex te, cause the applicati	nowever, may a reply be time minimum of thirty (30) days pire SIX (6) MONTHS from on to become ABANDONEI	nely filed s will be considered time the mailing date of this c D (35 U.S.C. § 133).			
Status							
1)[🛛	Responsive to communication(s) filed on 20 (October 2003.					
2a)□	This action is FINAL . 2b) This action is non-final.						
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposit	ion of Claims						
 4) Claim(s) 1-10 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) Claim(s) is/are allowed. 6) Claim(s) is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) 1-10 are subject to restriction and/or election requirement. 							
Applicat	ion Papers						
•	The specification is objected to by the Examin						
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.							
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority (under 35 U.S.C. § 119						
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 							
Attachmen	ut(s) ce of References Cited (PTO-892)		☐ Interview Summary	(PTO-413)			
2) Notice 3) Infor	ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08 er No(s)/Mail Date		Paper No(s)/Mail Da Notice of Informal P	ate	O-152)		

PApplication/Control Number: 10/689,332

Art Unit: 2872

Election/Restrictions

Restriction to one of the following inventions is required under 35 U.S.C. 121:

- Claims 1-4, drawn to a method for evaluating characteristics of the ion implantation in a shallow junction formed on a semiconductor sample, classified in class 356, subclass 369.
- II. Claims 5-10, drawn to a method of forming a shallow junction in a semiconductor wafer, classified in class 250, subclass 225.

The inventions are distinct, each from the other because of the following reasons:

Inventions I and II are related as subcombinations disclosed as usable together in a single combination. The subcombinations are distinct from each other if they are shown to be separately usable. In the instant case, invention I has separate utility such as a method for evaluating characteristics of the ion implantation in a shallow junction formed on a semiconductor sample. See MPEP § 806.05(d).

Because these inventions are distinct for the reasons given above and the search required for Group I is not required for Group II, restriction for examination purposes as indicated is proper.

A telephone call was made to Mr. Michael A Stallman on 7/7/04 to request an oral election to the above restriction requirement, but did not result in an election being made.

Applicant is advised that the reply to this requirement to be complete must include an election of the invention to be examined even though the requirement be traversed (37 CFR 1.143).

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CONTACT INFORMATION

Papers related to this application may be submitted to Group 2870 by facsimile transmission. Papers should be faxed to Group 2870 via the PTO Fax center located in the Crystal Plaza 4. Faxing of such papers must conform with the notice published in the official Gazette, 1096 OG 30 (November 15, 1989). The CP-4 Fax Center number is (703) 308-7722.

Any inquiry of a general nature or relating to the status of this application should be directed to M. Sikder whose telephone number is (571) 272-2321.

MOHAMMAD SIKDEH DRIMARY EXAMINER

Sunday, July 11, 2004